# Influence of Core Substitution on the Electronic Structure of Benzobisthiadiazoles

Mohsen Ajdari,<sup>†</sup> Ronja Pappenberger,<sup>†</sup> Caja Annweiler,<sup>†</sup> Tobias Kaczun,<sup>‡</sup> Leon

Müller,<sup>‡</sup> Larissa Winkelmann,<sup>†</sup> Lukas Ahrens,<sup>¶</sup> Uwe H. F. Bunz,<sup>¶</sup> Andreas Dreuw,<sup>‡</sup>

and Petra Tegeder\*,<sup>†</sup>

†Physikalisch-Chemisches Institut, Universität Heidelberg, Im Neuenheimer Feld 253, 69120 Heidelberg, Germany

‡Interdisziplinäres Zentrum für Wissenschaftliches Rechnen, Universität Heidelberg, Im Neuenheimer Feld 205A, 69120 Heidelberg, Germany

¶Organisch-Chemisches Institut, Universität Heidelberg, Im Neuenheimer Feld 270, 69120 Heidelberg, Germany

E-mail: tegeder@uni-heidelberg.de

Phone: +49 (0) 6221 548475

#### Abstract

Benzobisthiadiazoles (BBTs) are promising organic semiconductors for applications in field effect transistors and solar cells, since they possess a strong electron-accepting character. Thereby the electronic structure of organic/metal interfaces and within thin films is essential for the performance of organic electronic devices. Here, we study the structural and the electronic properties of two BBTs, with different core substitution pattern, a phenyl (BBT-Ph) and thiophene (BBT-Th) derivative adsorbed on Au(111) using vibrational and electronic high-resolution electron energy loss spectroscopy in combination with state-of-the-art quantum chemical calculations. In the mono- and multilayer both BBTs adopt a planar adsorption geometry with the molecular backbone as well as the phenyl and thiophene side groups are oriented parallel to the gold substrate. The energies of the lowest excited electronic singlet states (S) and the first triplet state  $(T_1)$  are determined. The optical gap  $(S_0 \rightarrow S_1 \text{ transition})$  is found to be 2.2 eV for BBT-Ph and 1.6 eV for BBT-Th. The energy of  $T_1$  is identified to be 1.2 eV in BBT-Ph and in the case of BBT-Th 0.7 eV. Thus, both the optical gap size as well as the  $T_1$  energy are drastically reduced in BBT-Th compared to BBT-Ph. Based on our quantum chemical calculations this is attributed to the electron-rich nature of the five-membered thiophene rings in conjunction with their preference for planar geometries. Variation of the substitution pattern in BBTs opens the opportunity for tailoring their electronic properties.

## Introduction

Benzo[1,2-c:4,5-c']bis[1,2,5]thiadiazole (BBT) containing polymers and small molecules are promising candidates for applications in organic (opto) electronic devices such as solar cells, light emitting diodes, or field effect transistors,<sup>1-4</sup> because they possess a strong electronaccepting character<sup>5</sup> and inherent small optical band gaps.<sup>6-9</sup> In addition, they show auspicious charge carrier mobilities, often ambipolar.<sup>2,10</sup> For device performance the molecular orientation at the interface to an electrode as well as within a molecular film (film morphology) plays an essential role, since it strongly influences the electronic properties such as energy level alignment or charge transport properties.<sup>11-24</sup> Utilizing high-resolution electron energy loss spectroscopy (HREELS) allows for the analysis of both the adsorption and electronic properties of molecules on (semi)metallic surfaces and within thin films.<sup>25-36</sup> HREELS has already been successfully applied to investigate the energies of intramolecular electronic transitions (e.g.  $S_0 \rightarrow S_1$ ).<sup>25-29,35,37,38</sup> Furhermore, HREELS opens up the opportunity to gain insights into the energetic position of triplet states,<sup>37,39-42</sup> which are not accessible with (linear) optical methods. While the adsorption and electronic properties of S-heteropolycyclic aromatic molecules in particular thiophene derivatives on metal substrates have been studied in great detail (see e.g. Refs.<sup>43–55</sup>) due to their relevance in vacuum-processed small molecule organic solar cells,<sup>56–60</sup> only a few examples of N-heteropolycycles are known in literature.<sup>28,29,36,38,41,42,61,62</sup> Notably, N-heteropolycyclic compounds are promising candidates for electron transporting (n-channel) semiconductors, which are of great interest as organic field effect transistors.<sup>63–67</sup> In the case of S- and N-containing heteropolycycles only one study is known in literature.<sup>37</sup> Therein, the structural and electronic properties of naphthothiadiazole derivatives adsorbed on Au(111) have been investigated with HREELS, in particular the influence of core halogenation on the electronic structure.<sup>37</sup> Several singlet and the first triplet transition energies have been determined. It has been found that halogenation leads to a decrease of the optical gap size.



Figure 1: Benzo[1,2-c:4,5-c']bis[1,2,5]thiadiazole (BBT) derivatives investigated in the present study.

In the present contribution we study the adsorption and electronic properties of two BBT derivatives, the phenyl substituted 4,8-diphenyl-benzo[1,2-c:4,5-c']bis[1,2,5]thiadiazole (BBT-Ph) and thiophene substituted 4,8-dithiophene-benzo[1,2-c:4,5-c']bis[1,2,5]thiadiazole (BBT-Th) shown in Fig. 1 on Au(111) using vibrational and electronic HREELS as well as state-of-the-art quantum chemical methodology. In particular we focus on the influence of core substitution (phenyl vs. thiophene) on the electronic structure. We found that both BBT derivatives in the monolayer and thin film adopt an adsorption geometry in which the molecular backbone and the side groups (phenyl or thiophene) are orient themselves parallel to the Au(111) substrate. For both derivatives several singlet transitions are identified as well as the first triplet state. Going from BBT-Ph to BBT-Th results in a pronounced reduction of the electronic transition energies.

## Methods

The HREELS experiments were performed under ultra-high vacuum conditions at a sample temperature of around 90 K. The Au(111) single crystal was prepared by standard procedure of Ar<sup>+</sup> sputtering and annealing. The BBT compounds were synthesized according to the procedures reported in Ref.<sup>68</sup> They were deposited from an effusion cell held at 443 K for BBT-Ph and at 468 K for BBT-Th onto the Au(111) sample held at 300 K. The coverage was determined by temperature-programmed desorption (TPD) measurements (see supporting information; Figs. S1 and S2)). While in the monolaver (ML) regime i.e., the molecules in direct contact with the metal substrate, BBT-Ph desorbs intact, the BBT-Th molecules are decaying as can be concluded from HREELS and scanning tunneling microscopy experiments (see supporting information; Figs. S3–S5), therefore the coverage determination for BBT-Th has a larger error. However, for both BBT-Ph a defined ML coverage can be prepared by adsorbing a multilayer followed by heating to 400 K to desorb the multilayer. For BBT-Th direct deposition of the molecules was used. HREELS measurements were performed with incident electron energy of 3.5 eV and 15 eV for vibrational and electronic HREELS, respectively. For experimental details see Refs.<sup>27–29,69,70</sup> To assign the vibrational modes of BBT-Ph and BBT-Th, density functional theory (DFT) calculations for the isolated molecules were carried out using the Gaussian09 package.<sup>71</sup> Thereby the standard B3LYP exchange-correlation (xc) functional and the 6-311G basis set were employed.

Initial input geometries were generated using the universal force field as implemented in  $Avogadro^{72}$  and then optimized using DFT<sup>73,74</sup> with the standard B3LYP<sup>75</sup> xc functional

and the aug-cc-pVDZ<sup>76–78</sup> basis set employing the D4 dispersion correction.<sup>79</sup> Frequency calculations were performed to confirm the nature of the stationary points as minima on the potential energy surface. The conductor-like polarizable continuum model (CPCM) was utilized to account for solvent effects of dichloromethane (DCM,  $\epsilon = 9.08$ ) and chloroform (CHCl<sub>3</sub>,  $\epsilon = 4.9$ ).<sup>80,81</sup> Excitation energies were calculated at the optimized ground state equilibrium geometries with the Tamm-Dancoff approximation (TDA)<sup>82</sup> to linear-response time-dependent DFT (TDDFT)<sup>83,84</sup> employing the BMK<sup>85</sup> xc-functional and aug-cc-pVDZ basis set.

## **Results and Discussion**

While the energy level alignment at metal/organic interfaces strongly depends on the electronic coupling between metal and molecular states, the electronic properties of the molecules in a film are strongly influenced by the strength of their intermolecular interactions. In addition, electronic properties are also highly affected by the molecular adsorption geometry, both at the interface as well as within the film. Therefore we first analyzed the adsorption properties of the BBT derivatives at the interface and within the thin films using vibrational HREELS.

#### Adsorption properties of benzobisthiadiazoles on Au(111)

In Figure 2 a) the HREEL spectra of 1 ML BBT-Ph measured in specular and 7.1° offspecular scattering geometry are displayed, while the respective data for a coverage of 11 ML (off-specular data have been measured at 4.8°) are presented in Figure 2 b). In addition, the calculated intensities and frequencies of vibrational modes possessing a transition dipole moment perpendicular to the molecular backbone are shown in Figure 2 c). These modes belong to the irreducible representation  $B_3$  of the  $D_2$  molecular point group of BBT-Ph. In the spectra of 1 ML and 11 ML three pronounced vibrations located around 499, 690,



Figure 2: Vibrational HREEL spectra recorded in specular (black) and off-specular (red) scattering geometry of a) 1 ML and b) 11 ML BBT-Ph adsorbed on Au(111).  $E_0$  is the primary energy of the incident electrons. The energy resolution of 36 cm<sup>-1</sup> is determined by the full width at half maximum (FWHM) of the elastic peak (zero energy loss peak). c) DFT-calculated intensities and frequencies of B<sub>3</sub>-symmetric vibrations which possess transition dipole moments perpendicular to the molecular backbone.

and 748 cm<sup>-1</sup> (values obtained for 1 ML BBT-Ph/Au(111)) are observed. These vibrational modes are dipole-active, i.e., the intensity ratio between specular and off-specular scattered electrons is high and dipole scattering is the main excitation mechanism. By comparing the vibrational HREEL spectrum with the DFT calculation, the vibrations can be assigned to a combined  $\gamma_{\omega}$ (C-C-C) and  $\gamma_{\omega}$ (C-H) wagging ( $\omega$ ) mode in the phenyl moieties (499 cm<sup>-1</sup>) and to  $\gamma_{\omega}$ (C-H) wagging vibrations in the phenyl side groups (690 and 748 cm<sup>-1</sup>) (for the assignment see Table 1 and the supporting information for the visualization of the vibrational modes, Fig. S6).

Another dipole active out-of-plane vibration is located at 926  $\rm cm^{-1}$  which is associated

Table 1: Vibrational modes in cm<sup>-1</sup> of BBT-Ph for 1 ML and 11 ML adsorbed on Au(111). The abbreviation da denotes dipole-active modes. In addition, DFT calculated frequencies based on the B3LYP functional and the 6-311G basis set of the gas phase molecules are displayed. Further abbreviations:  $\nu$  – stretching;  $\delta$  – deformation;  $\omega$  – wagging;  $\tau$  – twisting;  $\gamma$  – out-of-plane; Repr. – representation of the point group and in brackets corresponding orientation of the calculated dipole derivative vector with respect to the molecular geometry, y BBT-backbone axis, z residual group axis, x perpendicular to the BBT-Ph plane.

$1 { m ML}$	$11  \mathrm{ML}$	$\mathbf{DFT}$	Mode	Repr.
-	223	242	buckling	$B_2(y)$
-	307	294	$\delta(\text{C-C-C})$	$B_2(y)$
499~da	$510 \ da$	507	$\gamma_{\omega}(\text{C-C-C}), \gamma_{\omega}(\text{C-H})$	$B_3(x)$
690  da	694  da	711	$\gamma_{\omega}(\text{C-H})$	$B_3(x)$
$748 \ da$	762  da	809	$\gamma_{\omega}(\text{C-H})$	$B_3(x)$
-	866	865	$\omega$ (C-H)	$B_1(z)$
$926\ da$	$933 \ da$	953	$\gamma_{\omega}(\text{C-H})$	$B_3(x)$
1071	1092	1058	$\nu_s$ (C-C-C), $\delta$ (C-H)	$B_1(z)$
-	1192	1214	$\delta$ (C-H)	$B_2(y)$
-	1366	1367	$\nu$ (C-C-C), $\delta$ (C-H)	$B_2(y)$
-	1456	1459	$\nu(CN),  \delta(C-H)$	$B_1(z)$
3044	3071	3165	$\nu$ (C-H)	$B_1(z)$

with a  $\gamma_{\omega}$ (C-H) wagging mode in the phenyl side groups. Contrary, the intensity of the inplane  $\nu$ (C-H) stretching mode (3044 cm<sup>-1</sup>) shows no difference between dipole and impact scattered electrons. Thus, this mode is non-dipole active and accordingly impact scattering is the main excitation mechanism. Only one further in-plane vibration resulting from  $\nu$ (C-C-C) stretching vibration or  $\delta$ (C-H) deformation mode are detected at 1071 cm<sup>-1</sup>, which possesses a very low intensity. From these observations we conclude that in the monolayer regime BBT-Ph molecules adopt a planer adsorption geometry with the molecular backbone as well as the phenyl-rings oriented parallel to the Au(111) surface. It has be mentioned, that in the DFT calculations (after energy relaxation and geometry optimisation) the molecule is not arranged planar. The phenyl rings are twisted by 36.9° with respect to the planar molecular backbone. In comparison, in the BBT-Ph crystal structure an angle of 45.9° has been observed.<sup>8</sup> The planar adsorption geometry results in a change of the molecular point group from  $D_2$  to  $D_{2h}$ , which might be reason for the discrepancies between the vibrational transition energies attained from the DFT calculations in comparison to the experimental values (see Table 1). In the multilayer regime (Figure 2 b)), in addition to the very intense dipole-active modes found in the monolayer, several very low-intensity non-dipole active vibrations (below 510 cm<sup>-1</sup> and above 760 cm<sup>-1</sup>) are observed, which exhibit a dynamic dipole moment parallel to the surface indicating a slight tilting (or small disorder) of the molecular arrangement at higher coverage.



Figure 3: Vibrational HREEL spectra recorded in specular (black) and off-specular (red) scattering geometry of a) 1 ML and b) 5 ML BBT-Th/Au(111).  $E_0$  is the primary energy of the incident electrons. The energy resolution of 34 cm<sup>-1</sup> (36 cm<sup>-1</sup>) is determined by the full width at half maximum (FWHM) of the elastic peak (zero energy loss peak). c) DFT-calculated intensities and frequencies of A<sub>u</sub>-symmetric vibrations which possess transition dipole moments perpendicular to the molecular backbone.

The angle-resolved vibrational HREEL data for the BBT-Th in the mono- and multilayer regime as well as the calculated intensities and frequencies of vibrational modes possessing a dynamic dipole moment perpendicular to the molecular plane are displayed in Figure 3. In both the mono- and multilayer two very pronounced dipole active modes located at 490 and 713 cm<sup>-1</sup> for 1 ML BBT-Th/Au(111) can be assigned to the  $\gamma_{\tau}$ (C–C–C) out-of-plane twisting ( $\tau$ ) of the thiophene substituent as well as  $\gamma$ (C–N) mode (490 cm<sup>-1</sup>) and the  $\gamma_{\omega}$ (C– H) out-of-plane wagging mode of the thiophene moiety (713 cm<sup>-1</sup>) (see Table 2 for the assignment and the supporting information for the visualization of the vibrational modes, Fig. S7).

Table 2: Vibrational modes in cm<sup>-1</sup> of BBT-Th for 1 ML and 5 ML adsorbed on Au(111). The abbreviation da denotes dipole-active modes. In addition DFT calculated frequencies based on the B3LYP functional and the 6-311G basis set of the free molecules are displayed. Further abbreviations:  $\nu$  – stretching;  $\delta$  – deformation;  $\omega$  – wagging;  $\tau$  – twisting;  $\gamma$  – out-of-plane; Repr. – representation of the point group and in brackets corresponding orientation of the calculated dipole derivative vector with respect to the molecular geometry, x BBT-backbone axis, y residual group axis, z perpendicular to the BBT-Th plane.

$1  \mathrm{ML}$	$5 \mathrm{ML}$	$\mathbf{DFT}$	Mode	Repr.
-	$137 \ da$	161	$\gamma_{\tau}(\text{N-S-N})$	$A_u(z)$
$490 \ da$	$500 \ da$	488	$\gamma_{\tau}(\text{C-C-C}), \ \gamma(\text{CN})$	$A_u(z)$
$567 \ da$	$571 \ da$	585	$\gamma_{\tau}$ (C-C-C), $\gamma_{\tau}$ (C-H)	$A_u(z)$
$713 \ da$	719  da	724	$\gamma_{\omega}( ext{C-H})$	$A_u(z)$
829  da	$839 \ da$	815	$\gamma_{\omega}( ext{C-H})$	$A_u(z)$
874  da	-	899	$\gamma\omega/ au( ext{C-H})$	$A_u(z)$
-	1213	1276	$\delta$ (C-H), $\delta$ (C-C-C)	$B_u(x,y)$
-	1443	1493	$\nu$ (C-C), $\nu$ (CN), $\delta$ (C-C-C)	$B_u(x,y)$
-	3089	3204	$\nu$ (C-H)	$B_u(x,y)$

In the monolayer regime all observed vibrational losses are dipole-active, thus, as for the BBT-Ph, the BBT-Th molecules are adsorbed flat with the molecular backbone and the thiophene rings oriented parallel to the surface. Similar to BBT-Ph, further peaks with very low intensity appear in the mulitlayer spectrum above 1000 cm<sup>-1</sup> (Figure 3b)). They can be assigned to in-plane modes. The most striking difference between the ML and multilayer data is the appearance of a very intense dipole-active peak at 137 cm<sup>-1</sup>, which is attributed to the out-of-plane backbone twisting mode  $\gamma_{\tau}$ (N–S–N). This can be explained by a strong adsorbate/substrate interaction in the monolayer regime which may lead to a suppression of this vibration. Hence, decoupling of the molecules from the metallic substrate at higher coverages results in the observation of the vibrational mode.<sup>86</sup> However, we conclude that in the monolayer as well as in the multilayer regime the molecules adopt a planar adsorption

geometry (molecular backbone and the thiophene moieties) with respect to the surface plane.

### Electronic properties of benzobisthiadiazoles on Au(111)

For gaining comprehensive insights into the electronic structure of the BBTs, i.e., the identification and assignment of singlet and triplet transition energies and to analyze the influence of the different core substitution (phenyl vs. thiophene) we utilized electronic HREELS and state-of-the-art quantum chemical methods.

Figure 4 shows HREEL spectra of 1 ML and 11 ML BBT-Ph/Au(111) recorded with a primary electron energy of 15 eV. In the 1 ML BBT-Ph/Au(111) spectrum several transitions



Figure 4: Electronic HREEL spectra of a) 1 ML and b) 11 ML BBT-Ph/Au(111) measured with an incident electron energy of 15 eV and under specular-scattering geometry. The electronic transitions were fitted using Gaussian functions (red curves). The BBT-Ph UV/vis spectrum obtained in hexane is shown for comparison (purple curve).

are detected. They are located at 1.2, 2.0, 2.6, 3.4, and 4.1 eV (peak maximum). At a coverage of 11 ML some features are more pronounced. In the ML spectrum we assign based on our quantum chemical calculations (see below) the peak detected at 1.2 eV to the first

triplet state  $(T_1)$  of BBT-Ph. The peak at 2.0 eV is attributed to the  $S_0 \rightarrow S_1$  transition, thus to the optical gap in accordance with literature.<sup>9</sup> The feature at 2.6 eV is connected with the conventional surface plasmon (CSP) of the Au(111) surface.<sup>87,88</sup> The weak contributions at 3.4 and 4.1 eV are ascribed to molecular transitions. The former one gains intensity in the 11 ML spectrum as well as the  $S_0 \rightarrow S_1$  transition, because in the multilayer regime the molecules are electronically decoupled from the metallic substrate.<sup>27–29,36,37,41</sup> The decoupling also leads to an increase of the transition energies, for instance the optical gap size rises by 200 meV from 2.0 to 2.2 eV. The plasmonic contribution (CSP) is not observed in the multilayer data due to the surface sensitivity of HREELS, viz. only the uppermost layers are probed. On the basis of our quantum chemical calculations (see below) we assign the peak at 3.5 eV and 4.0 eV to the  $S_0 \rightarrow S_7$  and  $S_0 \rightarrow S_{10}$  transition, respectively.

Figure 5 a) summarizes the electronic transitions determined with electronic HREELS of 11 ML BBT-Ph/Au(111). The optical gap observed in the thin film is in agreement with the data measured with UV/vis spectroscopy in solution (see Figure 4 b)), only a small energy-shift (50 meV) is found. This suggests a relatively weak influence of the metal substrate (adsorbate/substrate interactions) and intermolecular forces (adsorbate/adsorbate interactions) on the electronic states in the BBT-Ph thin film.

On the basis of our quantum chemical calculations, the peak observed at 2.2 eV can be assigned to the  $S_0 \rightarrow S_1$  transition with  $\pi\pi^*$  character (see Figure 6 and Table 3). The transition around 3.5 eV corresponds to the  $S_0 \rightarrow S_7$  transition with  $n\pi^*$  character involving the nitrogen lone pairs and the BBT  $\pi$ -system. The excitation around 4.0 eV can be associated with the  $S_0 \rightarrow S_{10}$  transition with  $\pi\pi^*$  character involving both the backbone and the phenyl substituent. These assignments have been made for the equilibrium geometry of BBT with a torsion angle of 44.7° between the phenyl rings and the BBT backbone according to our calculations. The UV/vis absorption spectrum has been obtained in solution, while the HREEL spectrum has been measured in a thin molecular film. To account for these environmental effects the CPCM solvent model has been employed. Furthermore, since the



Figure 5: Electronic transitions determined with electronic HREELS at a) 11 ML BBT-Ph/Au(111) and b) 5 ML BBT-Th/Au(111). Among the singlet states  $S_1$ ,  $S_7$ , and  $S_{10}/S_9$  the energies of the energetically lowest triplet state  $(T_1)$  have been determined.

dielectric constant is likely higher in the multilayer compared to n-hexane solution, a higher dielectric constant, that of  $\text{CHCl}_3$  has been employed in our calculations. However, the effect of these different dielectric constants within the CPCM model is very small (see supporting information, Fig. S8).

Table 3:	Assignment of	of the electronic t	ransitions of	BBT-Ph	. Calcula	ted tra	insition	energies
(BMK/a	ug-cc-pVDZ)	are compared to	experimenta	l values o	obtained	with U	$\mathrm{VV/vis}$ (	(hexane)
absorpti	on spectrosco	py and HREELS.						

State	Character	Excitation energy [eV]			
		calc. $(CHCl_3)$	exp. $(UV/vis)$	$\exp$ . (HREELS)	
$S_1$	$\pi \to \pi^*$	2.17	2.2	2.2	
$S_7$	$n \to \pi^*$	3.96	3.5	3.5	
$S_{10}$	$\pi \to \pi^*$	4.46	4.2	4.0	



(c)  $S_0 \rightarrow S_{10}$  detachment (left) and attachment density (right)

Figure 6: Detachment and attachment densities of the transitions of BBT-Ph given in Table 3, obtained at the level of TDA/BMK/aug-cc-pVDZ, plotted with an isosurface value of 0.001.

In a next step we studied the thiophene substituted BBT to elucidate the influence on the electronic structure compared to BBT-Ph. Figure 7 shows the monolayer and multilayer (5 ML) HREELS data. In the monolayer regime four electronic transitions are detected located at 0.7, 1.3, 2.6, and 3.0 eV (peak maximum), which can be assigned to the first triplet state (0.7 eV), the  $S_0 \rightarrow S_1$  transition (optical gap, 1.3 eV), the CSP (2.6 eV) and  $S_0 \rightarrow S_7$  transition (3.0 eV) based on our calculations (see below). Compared to BBT-Ph, an even more pronounced blue-shift of the transition energies are found when going from the mono- to the multilayer. The optical gap size rises by 300 meV from 1.3 to 1.6 eV and also by 300 eV for the  $S_0 \rightarrow S_7$  transition due to decoupling effects from the metal surface. Furthermore, in the multilayer the electron energy loss peak assigned to the optical gap shows



Figure 7: Electronic HREEL spectra of a) 1 ML and b) 5 ML BBT-Th/Au(111) measured with an incident electron energy of 15 eV and under specular-scattering geometry. The electronic transitions were fitted using Gaussian functions (red curves). The BBT-Th UV/vis spectrum obtained in hexane is shown for comparison (purple curve).

apart from a pronounced intensity increase, a vibronic contribution, which is attributed to vibrational contributions of the symmetric  $\nu(C-C)$  and  $\nu(C-N)$  stretching modes, the socalled breathing modes of the molecular backbone, with frequencies around 1450  $cm^{-1}$  (ca. 180 meV). In addition, a feature at 3.8 eV is detected, which can be assigned to  $S_0 \rightarrow S_9$ transition according to our calculations (see below). The comparison with the UV/vis data obtained from BBT-Th in solution shows an overall agreement. However, peak shifts around 200 meV towards lower energies are found in the thin film compared to the molecules in solution due to adsorbate/adsorbate (lateral) interactions. These interactions are obviously much stronger in BBT-Th in comparison to BBT-Ph, where we observed only a red-shift of around 50 meV.

According to our calculations, BBT-Th exhibits a planar equilibrium geometry in contrast to BBT-Ph. The peak around 1.6 eV can be assigned to the  $S_0 \rightarrow S_1$  transition with  $\pi\pi^*$ character involving both the BBT backbone and the thiophene substituent (see Figure 8 and Table 4). The observed peaks at 3.3 eV and 3.8 eV can be assigned to the  $S_0 \rightarrow S_7$  and  $S_0 \rightarrow S_9$  transitions with  $\pi\pi^*$  character, respectively, of which the former is mostly centered at the BBT moiety while the latter involves both the backbone and substituent  $\pi$ -systems. The  $n\pi^*$  transition observed in BBT-Ph is a dark  $S_0 \rightarrow S_{10}$  excitation for BBT-Th (see supporting information). This excitation is destabilized with respect to the  $\pi\pi^*$  excitations in BBT-Th due to the interaction between the nitrogen and sulfur lone pairs within the molecular plane. Additionally, it becomes a dark transition due to the orthogonality of the nitrogen n orbitals and the  $\pi$ -system in the strictly planar geometry.

Table 4: Assignment of the electronic transitions of BBT-Th. Calculated transition energies (TDA/BMK/aug-cc-pVDZ) are compared to experimental values obtained with UV/vis (hexane) absorption spectroscopy and HREELS.

State	Character	Excitation energy [eV]			
		calc. $(CHCl_3)$	exp. $(UV/vis)$	$\exp$ . (HREELS)	
$S_1$	$\pi \to \pi^*$	1.68	1.9	1.6	
$S_7$	$\pi \to \pi^*$	3.91	3.5	3.3	
$S_9$	$\pi \to \pi^*$	3.99	3.7	3.8	



(c)  $S_0 \rightarrow S_9$  detachment (left) and attachment density (right)

Figure 8: Detachment and attachment densities of the transitions of BBT-Th given in Table 4, obtained at the level of TDA/BMK/aug-cc-pVDZ, plotted with an isosurface value of 0.001.

Comparing the BBT-Ph and BBT-Th experimentally determined transition energies most strikingly all energies are reduced, the higher-lying singlet states by 200 meV ( $S_7$  and  $S_{10}/S_9$ ), the optical gap ( $S_0 \rightarrow S_1$ ) even by 600 meV ( $S_1$ ) and the first triplet state ( $T_1$ ) energy by 500 meV (see Fig. 5). Our calculated shift of the  $S_0 \rightarrow S_1$  transition energy between BBT-Ph and BBT-Th is 0.49 eV. According to our calculations, two factors contribute to this shift. The first one is the different angle between the substituent (Ph or Th) and the BBT moiety. While BBT-Ph exhibits a tilting angle of 44.7°, BBT-Th is fully planar. The relationship between the tilting angle and the excited state energies can be seen in Figure 9. If both BBT-Ph and BBT-Th are in a planar geometry the difference in their  $S_0 \rightarrow S_1$  transition energy is reduced to only 0.25 eV.



Figure 9: Relationship between tilting angle and excited state energies. (a) BBT-Ph (BMK/aug-cc-pVDZ, solvent:  $CHCl_3$ ) optimized geometry has a tilting angle of 44.7°. (b) BBT-Th (BMK/aug-cc-pVDZ, solvent: DCM) optimized geometry is planar. The S<sub>7</sub> is taken from the relaxed geometry. For other angles the corresponding state with the same character as the S<sub>7</sub> is plotted.

If, however, an electron-withdrawing group, for example NO<sub>2</sub> is computationally introduced at the thiophene ring, the corresponding  $S_0 \rightarrow S_1$  transition energy is increased to 1.95 eV which is very close to that of planar BBT-Ph. This demonstrates the electron-rich nature of the five-membered thiophene ring is the second factor contributing to the red shift of the  $S_0 \rightarrow S_1$  transition in BBT-Th. It should further be noted that the calculated  $S_0 \rightarrow S_1$ transition energy of 1.93 eV for planar BBT-Ph is in good agreement with the experimental value of 2.0 eV observed with HREELS when a single monolayer is measured, for which a planar geometry has been determined (see above).

For the  $T_1$  state, an energy difference of 0.82 eV to the ground state for planar BBT-Ph and one of 0.97 eV for an angle of 44.7° has been calculated. Both of them are slightly lower than the experimentally observed one of 1.2 eV. For BBT-Th, a computed  $T_1$  energy of 0.6 eV is obtained which is in good agreement with the experimental value of 0.7 eV.

Again introducing an NO<sub>2</sub> substituent at the thiophene increases the triplet state energy to 0.7 eV. While still slightly lower than the  $T_1$  energy of planar BBT-Ph (0.82 eV), it again indicates the importance of the electron-rich nature of the thiophene ring. To further investigate the influence of the thiophene ring on the  $T_1$  energy computationally, we replaced it by pyrrole. Its relaxed geometry is again planar according to our calculations. Furthermore, it exhibits nearly the same  $T_1$  energy of 0.6 eV as BBT-Th, indicating that the sulfur atom is not the main reason for the low  $T_1$  energy but rather the electron-rich nature of five-membered rings in conjunction with their preference for planar geometries.

The S<sub>7</sub> transition energy is calculated to be 3.96 eV for BBT-Ph and 3.91 eV for BBT-Th. Both are blue shifted compared to the experimental value of around 3.5 eV (UV/vis in hexane). Unlike the S<sub>0</sub>  $\rightarrow$  S<sub>1</sub> transition energy, the higher lying transition is barely affected by the tilting angle as seen in Figure 9, with the S<sub>7</sub> transition energy decreasing only by 0.08 eV when going from 0° to 90° tilting angle.

Compared to the HREELS value the  $S_7$  transition energy is blue shifted by 0.2 eV in the UV/vis experiment and 0.6 eV in the calculations. The difference in excitation energies between BBT-Ph and BBT-Th in the HREELS experiment is not observed in either our calculations or the UV/vis spectra. Neither of these takes the gold surface or intermolecular effects from the multilayer into account. This indicates that the shift may originate from either the gold surface or interactions between the molecules within the layers.

## Conclusion

Two benzobisthiadiazole (BBT) derivatives, a phenyl (BBT-Ph) and a thiophene (BBT-Th) core substituted compound adsorbed on Au(111) have been investigated using vibrational and electronic HREELS as well as quantum chemical calculations, focussing on the influence of core substitution pattern on the electronic structure. Both BBTs have been found to absorb in a planar adsorption geometry on Au(111), in which the molecular backbone as well as the Ph- or Th-substituent is oriented parallel to the Au surface in the mono- as well as multilayer regime. We were able to assign several features observed in the electronic HREEL spectrum to the corresponding excited electronic states based on TDDFT calculations. The

optical gap  $(S_0 \rightarrow S_1 \text{ transition})$  is found to be 2.2 eV for BBT-Ph and 1.6 eV for BBT-Th. Thus, the change in the substitution pattern from phenyl to thiophene has led to a pronounced reduction of the optical gap size by 0.6 eV. In addition, the energy of the first triplet state, which is located at 1.2 eV in BBT-Ph is also decreased by 0.5 eV in BBT-Th (T<sub>1</sub> = 0.7 eV). Our calculations clearly demonstrated that the reason for the reduced transition energies in BBT-Th is the electron-rich nature of the five-membered rings in conjunction with their preference for planar geometries. Using different substitution pattern may pave the way for fine-tuning the electronic properties of BBTs at will.

## Supporting information

Temperature-programmed desorption data of BBT-Ph/Au(111) and BBT-Th/Au(111); additional HREELS data of BBT-Th/Au(111); scanning tunneling microscopy data of BBT-Th/Au(111); visualization of calculated vibrational modes of BBT-Ph and BBT-Th; calculated solvent effects on transition energies; calculated excitation energies and oscillator strengths

## Acknowledgments

Funding by the German Research Foundation (DFG) through the collaborative research center SFB 1249 "N-Heteropolycycles as Functional Materials" (project number 281029004-SFB 1249, projects A01, B01, and B06) is gratefully acknowledged.

## References

- Tam, T. L. D.; Wu, J. Benzo[1,2-c:4,5-c']Bis[1,2,5]Thiadiazoles in Organic Optoelectronics: A Mini-Review. J. Mol. Eng. Mat. 2015, 3, 15340003.
- (2) Yuen, J. D.; Fan, J.; Seifter, J.; Lim, B.; Hufschmid, R.; Heeger, A. J.; Wudl, F. High

Performance Weak Donor–Acceptor Polymers in Thin Film Transistors: Effect of the Acceptor on Electronic Properties, Ambipolar Conductivity, Mobility, and Thermal Stability. J. Am. Chem. Soc. **2011**, 133, 20799–20807.

- (3) Ye, F.; Chen, W.; Pan, Y.; Liu, S. H.; Yin, J. Benzobisthiadiazoles: From structure to function. Dyes and Pigments 2019, 171, 107746.
- (4) Tam, T. L. D.; Salim, T.; Li, H.; Zhou, F.; Mhaisalkar, S. G.; Su, H.; Lam, Y. M.; Grimsdale, A. C. From benzobisthiadiazole, thiadiazoloquinoxaline to pyrazinoquinoxaline based polymers: effects of aromatic substituents on the performance of organic photovoltaics. J. Mater. Chem. 2012, 22, 18528–18534.
- (5) Müller, M.; Koser, S.; Tverskoy, O.; F, R.; Freudenberg, J.; Bunz, U. H. F. Thiadiazolo-Azaacenes. Chem. Eur. J. 2019, 25, 6082–6086.
- (6) Thomas, A.; Bhanuprakash, K. Comparative Study of the Semiconducting Properties of Benzothiadiazole and Benzobis(thiadiazole) Derivatives Using Computational Techniques. *Chem. Phys. Chem.* **2012**, *13*, 597–605.
- (7) Chmovzh, T. N.; Knyazeva, E. A.; Mikhalchenko, L. V.; Golovanov, I. S.; Amelichev, S. A.; Rakitin, O. A. Synthesis of the 4,7-Dibromo Derivative of Highly Electron-Deficient [1,2,5]Thiadiazolo[3,4-d]pyridazine and Its Cross- Coupling Reactions. *Eur. J. Org. Chem.* **2018**, *2018*, 5668–5677.
- (8) Yamashita, Y.; Ono, K.; Tomura, M.; Tanaka, S. Synthesis and Properties of Benzobis(thiadiazole)s with Nonclassical π-Electron Ring Systems. *Tetrahedron* 1997, 53, 10178–10178.
- (9) Qian, G.; Wang, Z. Y. Near-Infrared Organic Compounds and Emerging Applications. Chem. As. J. 2010, 5, 1006–1029.

- (10) Yuen, J. D.; Kumar, R.; Zakhidov, D.; Seifter, J.; Lom, B.; Heeger, A. J.; Wudl, F. Ambipolarity in Benzobisthiadiazole-Based Donor–Acceptor Conjugated Polymers. Adv. Mater. 2011, 23, 3780–3785.
- (11) Ishii, H.; Sugiyama, K.; Ito, E.; Seki, K. Energy Level Alignment and Interfacial Electronic Structures at Organic/Metal and Organic/Organic Interfaces. Adv. Mater. 1999, 11, 605–625.
- (12) Koch, N., Ueno, N., Wee, A., Eds. The Molecule-Metal Interface; Wiley-VCH, Weinheim, 2013.
- (13) Gruenewald, M.; Wachter, K.; Meissner, M.; Kozlik, M.; Forker, R.; Fritz, T. Optical and Electronic Interaction at Metal–Organic and Organic–Organic Interfaces of Ultra-Thin Layers of PTCDA and SnPc on Noble Metal Surfaces. Org. Electron. 2013, 14, 2177–2183.
- (14) Braun, S.; Salaneck, W. R.; Fahlman, M. Energy-Level Alignment at Organic/Metal and Organic/Organic Interfaces. Adv. Mater. 2009, 21, 1450–1472.
- (15) Oehzelt, M.; Koch, N.; Heimel, G. Organic semiconductor density of states controls the energy level alignment at electrode interfaces. *Nature Comm.* 2014, 5, 4174.
- (16) Mercurio, G.; Maurer, R. J.; Liu, W.; Hagen, S.; Leyssner, F.; Tegeder, P.; Tkatchenko, J. M. A.; Soubatch, S.; Reuter, K.; Tautz, F. S. Quantification of Finite-Temperature Effects on Adsorption Geometries of π-Conjugated Molecules: Azobenzene/Ag(111). Phys. Rev. B 2013, 88, 035421.
- (17) Bredas, J. L.; Norton, J. E.; Cornil, J.; Coropceanu, V. Molecular Understanding of Organic Solar Cells: The Challenges. Acc. Chem. Res. 2009, 42, 1691–1699.
- (18) Köhler, A.; Bässler, H. *Electronic Processes in Organic Semiconductors*; Wiley-VCH: Weinheim, Germany, 2015.

- May, V.; Kühn, O. Charge and Energy Transfer Dynamics in Molecular Systems; Wiley-VCH: Weinheim, Germany, 2011.
- (20) Beljonne, D.; Cornil, J.; Muccioli, L.; Zannoni, C.; Brédas, J. L.; Castet, F. Electronic Processes at Organic–Organic Interfaces: Insight from Modeling and Implications for Opto-electronic Devices. *Chem. Mater.* **2011**, *23*, 591–609.
- (21) Ruhle, V.; Lukyanov, A.; May, F.; Schrader, M.; Vehoff, T.; Kirkpatrick, J.; Baumeier, B.; Andrienko, D. Microscopic Simulations of Charge Transport in Disordered Organic Semiconductors. J. Chem. Theory Comput. 2011, 7, 3335–3345.
- (22) D'Avino, G.; Muccioli, L.; Castet, F.; Poelking, C.; Andrienko, D.; Soos, Z. G.; Cornil, J.; Beljonne, D. Electrostatic Phenomena in Organic Semiconductors: Fundamentals and Implications for Photovoltaics. J. Phys.: Condens. Matter 2016, 28, 433002.
- (23) Casu, M. B. Growth, Structure, and Electronic Properties in Organic Thin Films Deposited on Metal Surfaces Investigated by Low Energy Electron Microscopy and Photoelectron Emission Microscopy. J. Elect. Spec. Rel. Phenom. 2015, 204, 39–48.
- (24) Forker, R.; Gruenewald, M.; Fritz, T. Optical Differential Reflectance Spectroscopy on Thin Molecular Films. Annu. Rep. Prog. Chem., Sect. C: Phys. Chem. 2012, 108, 34–68.
- (25) Bronner, C.; Leyssner, F.; S.Stremlau,; Utecht, M.; Saalfrank, P.; Klamroth, T.; Tegeder, P. Electronic Structure of a Subnanometer wide Bottom-up Fabricated Graphene Nanoribbon: End States, Band Gap, and Dispersion. *Phys. Rev. B: Condens. Matter Mater. Phys.* **2012**, *86*, 085444.
- (26) Bronner, C.; Stremlau, S.; Gille, M.; Brauße, F.; Haase, A.; Hecht, S.; Tegeder, P. Aligning the Band Gap of Graphene Nanoribbons by Monomer Doping. Angew. Chem., Int. Ed. 2013, 52, 4422–4425.

- (27) Maaß, F.; Utecht, M.; Stremlau, S.; Gille, M.; Schwarz, J.; Hecht, S.; Klamroth, T.; Tegeder, P. Electronic Structure changes during the on-surface synthesis of nitrogendoped chevron-shaped graphene nanoribbons. *Phys. Rev. B* 2017, *96*, 045434.
- (28) Maass, F.; Stein, A.; Kohl, B.; Hahn, L.; Gade, L. H.; Mastalerz, M.; Tegeder, P. Substrate-Directed Growth of N-Heteropolycyclic Molecules on a Metal Surface. J. Phys. Chem. C 2016, 120, 2866–2873.
- (29) Hahn, L.; Maass, F.; Bleith, T.; Zschieschang, U.; Wadepohl, H.; Klauk, H.; Tegeder, P.;
  Gade, L. H. Core Halogenation as a Construction Principle in Tuning the Material Properties of Tetraazaperopyrenes. *Chem. Eur. J.* 2015, *21*, 17691–17700.
- (30) Stein, A.; Maaß, F.; Tegeder, P. Triisopropylsilylethynyl-Pentacene on Au(111): Adsorption Properties, Electronic Structure, and Singlet Fission Dynamics. J. Phys. Chem. C 2017, 121, 18075–18083.
- (31) Stremlau, S.; Maass, F.; Tegeder, P. Adsorption and switching properties of nitrospiropyran on Bi(114). J. Phys.: Condens Matter 2017, 29, 314004.
- (32) Gahl, C.; Brete, D.; Leyssner, F.; Koch, M.; McNellis, E. R.; Mielke, J.; Carley, R.; Grill, L.; Reuter, K.; Tegeder, P.; Weinelt, M. Coverage- and Temperature-Controlled Isomerization of an Imine Derivative on Au(111). J. Am. Chem. Soc. 2013, 135, 4273–4281.
- (33) Leyssner, F.; Hagen, S.; Óvári, L.; Dokic, J.; Saalfrank, P.; Peters, M. V.; Hecht, S.; Klamroth, T.; Tegeder, P. Photoisomerization ability of molecular switches adsorbed on Au(111): Comparison between azobenzene and stilbene derivatives. J. Phys. Chem. C 2010, 114, 1231–1239.
- (34) Ovári, L.; Wolf, M.; Tegeder, P. Reversible Changes in the Vibrational Structure of of tetra-tert-butylazobenzene on a Au(111) Surface Induced by Light and Thermal Activation. J. Phys. Chem. C 2007, 111, 15370–15374.

- (35) Navarro, P.; Bocquet, F. C.; Deperasinska, I.; Pirug, I.; Tautz, F. S.; Orrit, M. Electron Energy Loss of Terrylene Deposited on Au(111): Vibrational and Electronic Spectroscopy. J. Phys. Chem. C 2014, 119, 277–283.
- (36) Ajdari, M.; Stein, A.; Hoffmann, M.; Müller, M.; Bunz, U. H. F.; Dreuw, A.; Tegeder, P. Lightening up a Dark State of a Pentacene Derivative via N-Introduction. J. Phys. Chem. C 2020, 124, 7196–7204.
- (37) Ajdari, M.; Landwehr, F.; Hoffmann, M.; Hoffmann, H.; Bunz, U. H. F.; Dreuw, A.; Tegeder, P. Influence of Core Halogenation on the Electronic Structure of Naphthothiadiazole Derivatives. J. Phys. Chem. C 2021, 125, 6359–6366.
- (38) Ajdari, M.; Pappenberger, R.; Walla, C.; Hoffmann, M.; Michalsky, I.; Kivala, M.; Dreuw, A.; Tegeder, P. Impact of Connectivity on the Electronic Structure of N-Heterotriangulenes. J. Phys. Chem. C 2023, 127, 542–549.
- (39) Swiderek, P.; Michaud, M.; Hohlneicher, G.; Sanche, L. Electron Energy Loss Spectroscopy of Solid Naphthalene and Acenaphthene: Search for the Low-Lying Triplet States. *Chem. Phys. Lett.* **1990**, *175*, 667–673.
- (40) Swiderek, P.; Fraser, M.-J.; Michaud, M.; Sanche, L. Electron-Energy-Loss Spectroscopy of Low-Lying Triplet States of Styrene. J. Chem. Phys. 1994, 100, 70–77.
- (41) Ajdari, M.; Schmitt, T.; Hoffmann, M.; Maass, F.; Reiss, H.; Bunz, U. H. F.; Dreuw, A.; Tegeder, P. Electronic Properties of 6, 13-Diazapentacene Adsorbed on Au(111): A Quantitative Determination of Transport, Singlet and Triplet States and Electronic Spectra. J. Phys. Chem. C 2020, 124, 13196–13205.
- (42) Hoffmann, M.; Ajdari, M.; Landwehr, F.; Tverskoy, O.; Bunz, U. H. F.; Dreuw, A.; Tegeder, P. Influence of N-introduction in pentacene on the electronic stracture and excited electronic states. *Phys. Chem. Chem. Phys.* **2022**, *24*, 3924–3932.

- (43) Hill, I.; Kahn, A.; Soosb, Z.; R.A. Pascal, J. Charge-separation energy in films of πconjugated organic molecules. *Chem. Phys. Lett.* **2000**, *327*, 181–188.
- (44) Koch, N.; Heimel, G.; Wu, J.; Zojer, E.; Johnson, R. L.; Brédas, J.-L.; Müllen, K.; Rabe, J. P. Influence of molecular conformation on organic/metal interface energetics. *Chem Phys. Lett.* 2005, 413, 390–395.
- (45) Kiguchi, M.; Entani, S.; Saiki1, K.; Yoshikawa, G. One-dimensional ordered structure of α-sexithienyl on Cu(110). Appl. Phys. Lett. 2004, 84, 3444–3446.
- (46) Yokoyama, T.; Kurata, S.; Tanaka, S. Direct identification of conformational isomers of adsorbed oligothiophene on Cu(100). J. Phys. Chem. B 2006, 110, 18130.
- (47) Kakudate, T.; Tsukamoto, S.; Nakaya, M.; Nakayama, T. Initial stage of adsorption of octithiophene molecules on Cu(111). Surf. Sci. 2006, 605, 1021–1026.
- (48) Kiel, M.; Duncker, K.; Hagendorf, C.; Widdra, W. Molecular structure and chiral separation in α-sexithiophene ultrathin films on Au(111): Low-energy electron diffraction and scanning tunneling microscopy. *Phys. Rev. B* 2007, 75, 195439.
- (49) Grobosch, M.; Knupfer, M. Charge-Injection Barriers at Realistic Metal/Organic Interfaces: Metals Become Faceless. Adv. Mater. 2007, 19, 754.
- (50) Varene, E.; Martin, I.; Tegeder, P. Optically Induced Inter- and Intrafacial Electron Transfer Probed by Two-Photon Photoemission: Electronic States of Sexithiophene on Au(111). J. Phys. Chem. Lett. 2011, 2, 252–256.
- (51) Varene, E.; Bogner, L.; Bronner, C.; Tegeder, P. Ultrafast exciton population, relaxation and decay dynamics in thin oligothiophene films. *Phys. Rev. Lett.* **2012**, *109*, 207601.
- (52) Varene, E.; Bogner, L.; Meyer, S.; Pennec, Y.; Tegeder, P. Coverage-dependent adsorption geometry of octithiophene on Au(111). *Phys. Chem. Chem. Phys.* 2012, 14, 691–696.

- (53) Bogner, L.; Yang, Z.; Corso, M.; Fitzner, R.; Bäuerle, P.; Franke, K. J.; Pascual, J. I.; Tegeder, P. Electronic Structure and Excited State Dynamics in a Dicyanovinyl-Substituted Oligothiophene on Au(111). *Phys. Chem. Chem. Phys.* 2015, 17, 27118– 27126.
- (54) Bogner, L.; Yang, Z.; Baum, S.; Corso, M.; Fitzner, R.; Bäuerle, P.; Franke, K. J.;
  Pascual, J. I.; Tegeder, P. Electronic States and Exciton Dynamics in Dicyanovinyl-Sexithiophene on Au(111). J. Phys. Chem. C 2016, 120, 27268–27275.
- (55) Bronsch, W.; Wagner, T.; Baum, S.; Wansleben, M.; Zielke, K.; Ghanbari, E.; Györök, M.; Navarro-Quezada, A.; Zeppenfeld, P.; Weinelt, M.; Gahl, C. Interplay between Morphology and Electronic Structure in Sexithiophene Films on Au(111). J. Phys. Chem. C 2019, 123, 7931–7939.
- (56) Mishra, A.; Uhrich, C.; Reinold, E.; Pfeiffer, M.; Bäuerle, P. Synthesis and Characterization of Acceptor-substituted Oligothiophenes for Solar Cell Applications. Adv. Energy Mater. 2011, 1, 265–273.
- (57) Ziehlke, H.; Fitzner, R.; Körner, C.; Gresser, R.; Reinold, E.; Bäuerle, P.; Leo, K.; Riede, M. Side Chain Variations on a Series of Dicyanovinyl-Terthiophenes: A Photoinduced Absorption Study. J. Phys. Chem. A 2011, 115, 8437–8446.
- (58) Fitzner, R.; Reinold, E.; Mishra, A.; Mena-Osteritz, E.; Ziehlke, H.; Körner, C.; Leo, K.; Riede, M.; Weil, M.; Tsaryova, O.; et al., Dicyanovinyl-Substituted Oligothiophenes: Structure-Property Relationships and Application in Vacuum-Processed Small-Molecule Organic Solar Cells. Adv. Funct. Mater. 2011, 21, 897–910.
- (59) Fitzner, R.; Mena-Osteritz, E.; Mishra, A.; Schulz, G.; Reinold, E.; Weil, M.; Körner, C.; Ziehlke, H.; Elschner, C.; Leo, K.; et al., Correlation of π-Conjugated Oligomer Structure with Film Morphology and Organic Solar Cell Performance. J. Am. Chem. Soc. 2012, 134, 11064–11067.

- (60) Meerheim, R.; Körner, C.; Leo, K. Highly Efficient Organic Multi-Junction Solar Cells with a Thiophene Based Donor Material. Appl. Phys. Lett. 2014, 105, 063306.
- (61) Stein, A.; Rolf, D.; Lotze, C.; Günther, B.; Gade, L. H.; Franke, K. J.; Tegeder, P. Band Formation at Interfaces Between N-Heteropolycycles and Gold Electrodes. J. Phys. Chem. Lett. 2021, 12, 947–951.
- (62) Stein, A.; Rolf, D.; Lotze, C.; Feldmann, S.; Gerbert, D.; Günther, B.; Jeindl, A.; Cartus, J. J.; Hofmann, O. T.; Gade, L. H.; Franke, K. J.; Tegeder, P. Electronic Properties of Tetraazaperopyrene Derivatives on Au(111): Energy Level Alignment and Interfacial Band Formation. J. Phys. Chem. C 2021, 125, 19969–19979.
- (63) Klauk, H.; Zschieschang, U.; Pflaum, J.; Halik, M. Ultralow-power organic complementary circuits. *Nature* 2007, 445, 745–748.
- (64) Würthner, F.; Stolte, M. Naphthalene and perylene diimides for organic transistors. *Chem. Commun.* 2011, 47, 5109–5115.
- (65) Bunz, U. H. F.; Engelhart, J. U.; Lindner, B. D.; Schaffroth, M. Large N-Heteroacenes: New Tricks for Very Old Dogs? Angew. Chem. Int. Ed. 2013, 52, 3810–3821.
- (66) Miao, Q. Ten Years of N-Heteropentacenes as Semiconductors for Organic Thin-Film Transistors. Adv. Mater. 2014, 26, 5541–5549.
- (67) Bunz, U. H. F. The larger linear N-heteroacenes. Acc. Chem. Res. 2015, 48, 1676–1686.
- (68) Li, H.; Tam, T. L.; Lam, Y. M.; Mhaisalkar, S. G.; Grimsdale, A. C. Synthesis of Low Band Gap [1,2,5]-Thiadiazolo[3,4-g]quinoxaline Derivatives by Selective Reduction of Benzo[1,2-c;4,5-c']bic[1,2,5]thiadiazole. Org. Lett. 2011, 13, 46–49.
- (69) Ibach, H.; Mills, D. L. Electron Energy Loss Spectroscopy and Surface Vibrations; Academic Press, New York, 1982.

- (70) Tegeder, P. Optically and Thermally Induced Molecular Switching Processes at Metal Surfaces. J. Phys.: Condens. Matter 2012, 24, 394001.
- (71) Frisch, M. et al. Gaussian 09, Revision A. 02, Gaussian. Inc., Wallingford, CT 2009, 200.
- (72) Hanwell, M. D.; Curtis, D. E.; Lonie, D. C.; Vandermeersch, T.; Zurek, E.; Hutchison, G. R. Avogadro: An Advanced Semantic Chemical Editor, Visualization, and Analysis Platform. 4, 17.
- (73) Hohenberg, P.; Kohn, W. Inhomogeneous Electron Gas. 136, B864–B871.
- (74) Kohn, W.; Sham, L. J. Self-Consistent Equations Including Exchange and Correlation Effects. 140, A1133–A1138.
- (75) Becke, A. D. Density-functional Thermochemistry. III. The Role of Exact Exchange. 98, 5648–5652.
- (76) Woon, D. E.; Dunning, T. H., Jr. Gaussian Basis Sets for Use in Correlated Molecular Calculations. III. The Atoms Aluminum through Argon. 98, 1358–1371.
- (77) Kendall, R. A.; Dunning, T. H., Jr.; Harrison, R. J. Electron Affinities of the First-row Atoms Revisited. Systematic Basis Sets and Wave Functions. 96, 6796–6806.
- (78) Dunning, T. H., Jr. Gaussian Basis Sets for Use in Correlated Molecular Calculations.I. The Atoms Boron through Neon and Hydrogen. 90, 1007–1023.
- (79) Caldeweyher, E.; Ehlert, S.; Hansen, A.; Neugebauer, H.; Spicher, S.; Bannwarth, C.; Grimme, S. A Generally Applicable Atomic-Charge Dependent London Dispersion Correction Scheme. https://chemrxiv.org/engage/chemrxiv/article-details/ 60c74060f96a006646286291.
- (80) Neese, F. Software Update: The ORCA Program System, Version 4.0. 8, e1327.

- (81) Barone, V.; Cossi, M. Quantum Calculation of Molecular Energies and Energy Gradients in Solution by a Conductor Solvent Model. 102, 1995–2001.
- (82) Hirata, S.; Head-Gordon, M. Time-Dependent Density Functional Theory within the Tamm–Dancoff Approximation. 314, 291–299.
- (83) Dreuw, A.; Head-Gordon, M. Single-Reference Ab Initio Methods for the Calculation of Excited States of Large Molecules. 105, 4009–4037.
- (84) Herbert, J. M. Density Functional Theory for Electronic Excited States; pp 69–118.
- (85) Boese, A. D.; Martin, J. M. L. Development of Density Functionals for Thermochemical Kinetics. 121, 3405–3416.
- (86) Kato, H. S.; Noh, J.; Hara, M.; Kawai, M. An HREELS Study of Alkanethiol Self-Assembled Monolayers on Au(111). J. Phys. Chem. B 2002, 106, 9655–9658.
- (87) Park, S. J.; Palmer, R. E. Plasmon Dispersion of the Au(111) Surface with and without Self-Assembled Monolayers. *Phys. Rev. Lett.* **2009**, *102*, 216805.
- (88) Park, S. J.; Palmer, R. E. Acoustic plasmon on the Au (111) surface. *Phys. Rev. Lett.* 2010, 105, 016801.



Figure : TOC Graphic